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FDB039N06 N-Channel PowerTrench[®] MOSFET 60 V, 174 A, 3.9 mΩ

Features

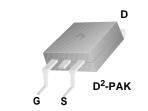
- $R_{DS(on)} = 2.95 \text{ m}\Omega$ (Typ.) @ $V_{GS} = 10 \text{ V}$, $I_D = 75 \text{ A}$
- Fast Switching Speed
- Low Gate Charge
- High Performance Trench Technology for Extremely Low $R_{\text{DS}(\text{on})}$
- High Power and Current Handling Capability
- RoHS Compliant

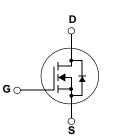
General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor[®]'s advanced PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor drives and Uninterruptible Power Supplies
- Renewable system





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol		Parameter		FDB039N06	Unit	
V _{DSS}	Drain to Source Voltage	Drain to Source Voltage			V	
V _{GSS}	Gate to Source Voltage	Source Voltage			V	
ID		-Continuous (T _C = 25 ^o C, Silicion	Limited)	174*		
	Drain Current	-Continuous (T _C = 100 ^o C, Silicio	n Limited)	123*	А	
		-Continuous (T _C = 25 ^o C, Packag	je Limited)	120		
I _{DM}	Drain Current	- Pulsed	(Note 1)	696	А	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		(Note 2)	872	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	7.0	V/ns	
P _D	Dawar Diasinatian	$(T_{C} = 25^{\circ}C)$		231	W	
	Power Dissipation	- Derate above 25°C		1.54	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +175	°C	
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C	

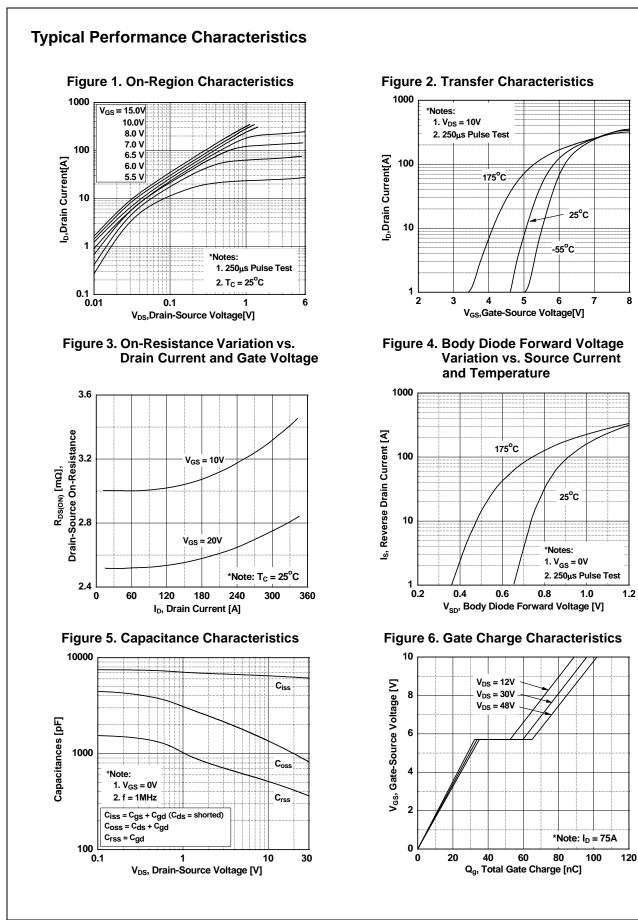
*Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 120A.

Thermal Characteristics

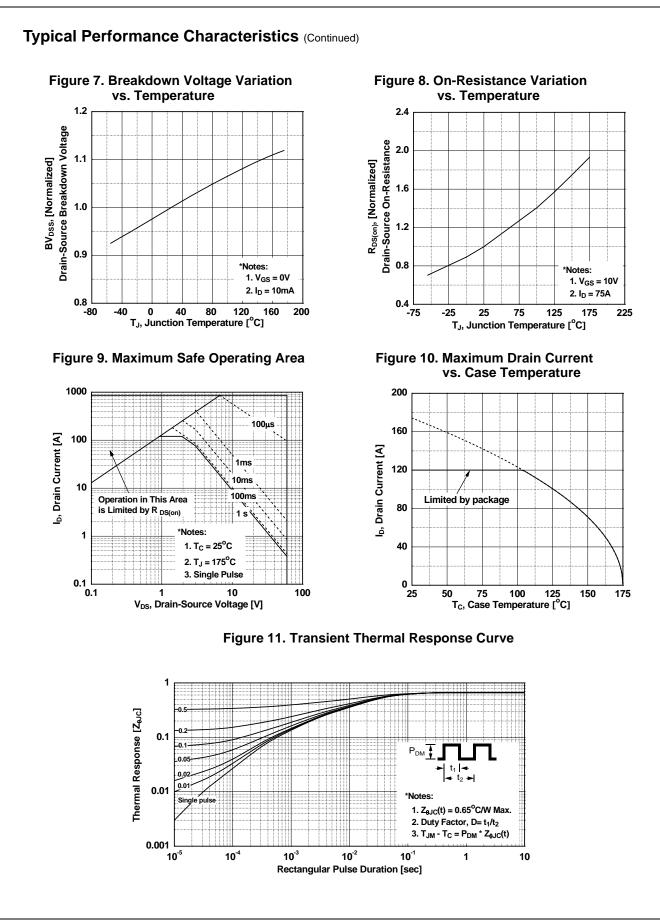
Symbol	Parameter	FDB039N06	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.65	
D	Thermal Resistance, Junction to Ambient (minimum pad of 2 oz copper), Max.	62.5	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient (1 in ² pad of 2 oz copper), Max.	40	

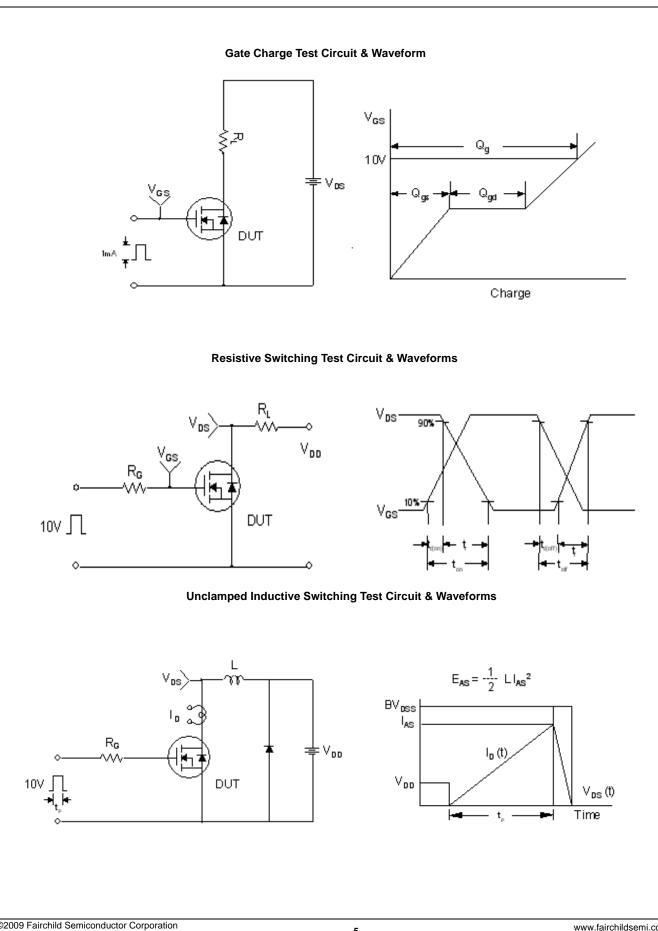
Device Marking		Device	Package	Reel Size	Тар	e Width		Quantit	у
FDB039	<u> </u>		TO-263	Tube		-		50	
Electrica	I Char	acteristics T _c =	25°C unless of	therwise noted	U				
Symbol	-			Test Conditions		Min.	Тур.	Max.	Unit
Off Charac	teristic	S						1	
BV _{DSS}	Drain to Source Breakdown Voltage		oltage	I _D = 250μA, V _{GS} = 0V, T _C = 25 ^o C		60	-	-	V
$\frac{\Delta BV_{DSS}}{\Delta T_{,l}}$	Breakdown Voltage Temperature Coefficient			$I_D = 250 \mu$ A, Referenced to 25° C		-	0.04	-	V/ºC
				$V_{DS} = 60V, V_{GS} = 0V$		-	-	1	
IDSS	Zero Ga	Zero Gate Voltage Drain Current		$V_{DS} = 60V, V_{GS} = 0V, T_{C} = 150^{\circ}C$		-	-	500	μΑ
I _{GSS}	Gate to	e to Body Leakage Current		$V_{GS} = \pm 20V, V_{DS} = 0V$		-	-	±100	nA
On Charac	teristic	5							
V _{GS(th)}	Gate Th	Gate Threshold Voltage		V _{GS} = V _{DS} , I _D = 250μA		2.5	3.5	4.5	V
R _{DS(on)}	Static D	rain to Source On Res		V _{GS} = 10V, I _D = 75A	-	2.95	3.9	mΩ	
9 _{FS}	Forward	d Transconductance		$V_{DS} = 10V, I_D = 75A$		-	169	-	S
Dynamic C							6400	0005	
C _{iss}		apacitance		V _{DS} = 25V, V _{GS} = 0V f = 1MHz		-	6190	8235 1195	pF
C _{oss}		Capacitance Transfer Capacitance				-	900 385	580	pF pF
C _{rss}		ate Charge at 10V				-	102	133	p⊢ nC
Q _{g(tot)}		Source Gate Charge		$V_{DS} = 48V, I_D = 75A$ $V_{GS} = 10V$ (Note 4)		-	32	-	nC
Q _{gs} Q _{gd}		Drain "Miller" Charge				_	32	-	nC
Switching		Ŭ			. , ,		02		no
t _{d(on)}		Delay Time				-	30	70	ns
t _r		Rise Time	,	$V_{DD} = 30V, I_D = 75A$ $V_{GS} = 10V, R_{GEN} = 4.7\Omega$ (Note 4)		-	40	90	ns
t _{d(off)}	Turn-Off	Delay Time				-	55	120	ns
t _f		Fall Time				-	24	58	ns
•		le Characteristic	·e		. ,			I	I
Drain-Sou			-	Forward Current		-	-	174	Α
	Maximu	m Continuous Drain to							
I _S		m Continuous Drain to m Pulsed Drain to Sou		ard Current		-	-	696	A
I _S I _{SM}	Maximu	m Pulsed Drain to Sou	Irce Diode Forw			-	-	696 1.3	A V
I _S	Maximur Drain to		urce Diode Forw d Voltage	vard Current $V_{GS} = 0V, I_{SD} = 75A$ $V_{GS} = 0V, I_{SD} = 75A$			- - 41		

FDB039N06 N-Channel PowerTrench[®] MOSFET

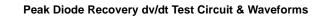


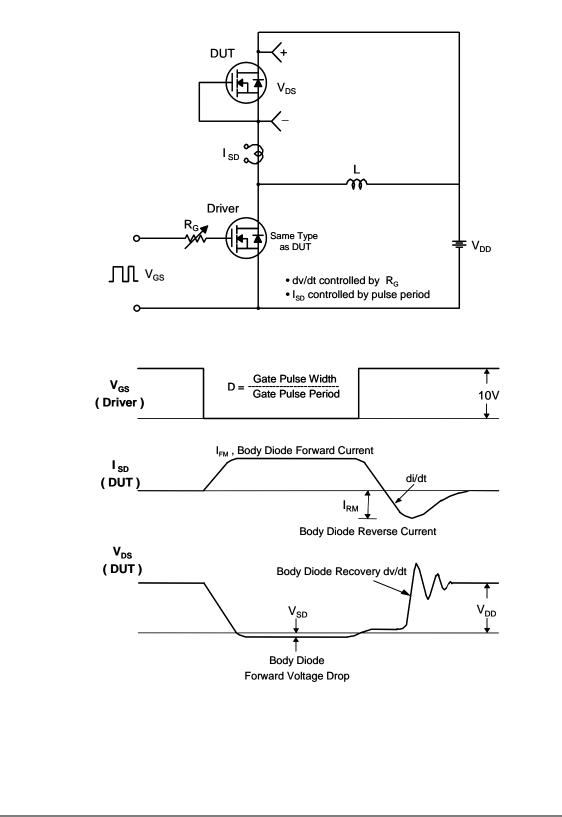
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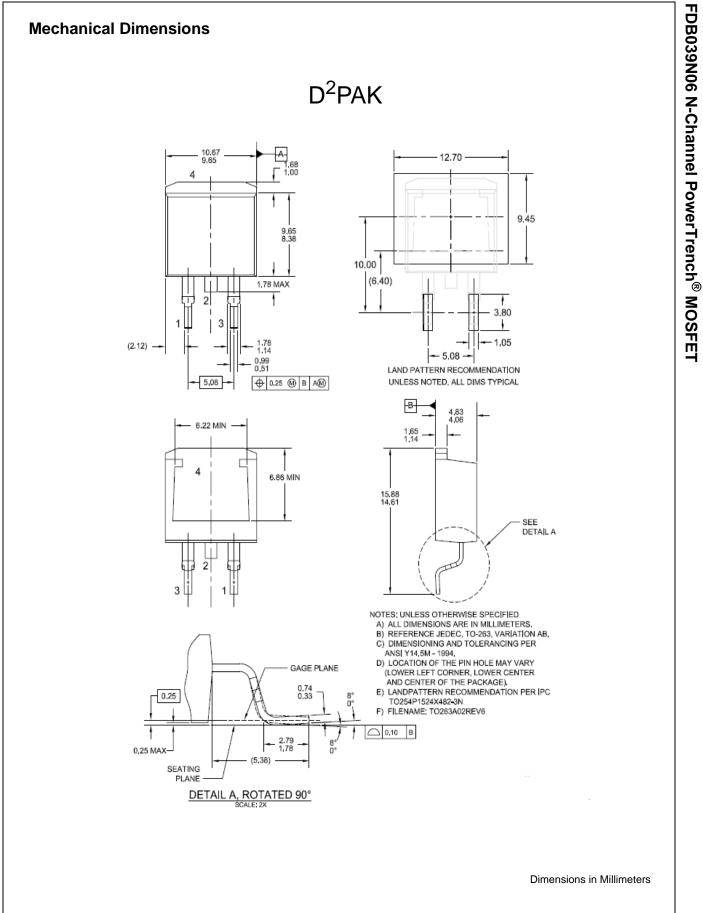




FDB039N06 N-Channel PowerTrench[®] MOSFET







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